

# Alpha & Omega Semiconductor Product Reliability qualification Report

AOZ2295QI-05, rev A

**Plastic Encapsulated Device** 

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This AOS product reliability report summarizes the qualification results for AOZ2295QI-05 in QFN4x4\_31L package. Accelerated environmental tests are performed on a specific sample size and samples are electrically tested before and after each time point. Review of final electrical test results confirm that AOZ2295QI-05 pass the AOS quality and reliability requirements. The released products will be categorized by its process family and routinely monitored for continuous improvement of product quality.

### I. Reliability Stress Test Summary and Results

Test Item	Test Condition	Time Point	Total Sample Size	Number of Failures	Reference Standard
HTOL	T <sub>J</sub> = 125°C, V <sub>IN</sub> = Vccmax	168 / 500 / 1000 hours	231 pcs	0	JESD22-A108
Preconditioning (Note A)	T <sub>A</sub> = 30°C, RH = 60% + 3 cycle reflow @ 260°C (MSL 3)	192 hours	924 pcs	0	JESD22-A113
HAST	T <sub>A</sub> = 130°C, RH = 85%, P = 33.3psia, V <sub>IN</sub> = Vccmax	96 hours	231 pcs	0	JESD22-A110
Autoclave	T <sub>A</sub> = 121°C, RH = 100%, P = 29.7psia	96 hours	231 pcs	0	JESD22-A102
Temperature Cycle	T <sub>A</sub> = -65°C to 150°C, air to air	250 / 500 / 1000 cycles	231 pcs	0	JESD22-A104
HTSL	Temp = 150°C	168 / 500 / 1000 hours	231 pcs	0	JESD22-A103

**Note:** The reliability data presents total of available generic data up to the published date. Note A: MSL (Moisture Sensitivity Level) 3 based on J-STD-020

#### II. Reliability Evaluation

FIT rate (per billion): 50.97

MTTF = 2240 years

The presentation of FIT rate for the individual product reliability is restricted by the actual burn-in sample size. Failure Rate Determination is based on JEDEC Standard JESD 85. FIT means one failure per billion hours.

Failure Rate =  $Chi^2 \times 10^9 / [2 (N) (H) (Af)] = 50.97$ MTTF =  $10^9 / FIT = 2240$  years

**Chi**<sup>2</sup> = Chi Squared Distribution, determined by the number of failures and confidence interval **N** = Total Number of units from burn-in tests

**H** = Duration of burn-in testing

Af = Acceleration Factor from Test to Use Conditions (Ea = 0.7eV and  $T_{use} = 55$ °C)

Acceleration Factor  $[Af] = Exp [Ea / k (1/T_J u - 1/T_J s)]$ 

#### **Acceleration Factor ratio list:**

	55 deg C	70 deg C	85 deg C	100 deg C	115 deg C	125 deg C
Af	77	26	9.8	3.9	1.7	1

T<sub>J</sub> s = Stressed junction temperature in degree (Kelvin), K = C + 273.16

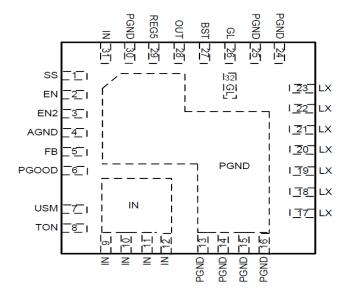


 $T_J u$  =The use junction temperature in degree (Kelvin), K = C + 273.16  $\mathbf{k}$  = Boltzmann's constant, 8.617164 X 10<sup>-5</sup>eV / K

## III. ESD and Latch Up Test Results

Test	Test Conditions	Total Sample Size	Number of Failures	Reference Standard
Electrostatic Discharge Human Body Model	25±5℃ 55±5%RH (±)2500V	15 pcs	0	JS-001-2017
Electrostatic Discharge Charged Device Model	25±5℃ 55±5%RH (±)1000V	6 pcs	0	JS-002-2018
Latch Up	25±5℃ 55±5%RH (±)200mA	9 pcs	0	JESD78
Latch Up	125±5℃ 55±5%RH (±)200mA	9 pcs	0	JESD78

(1) ATE results are used to determine PASS/FAIL. Parametric shift <10%.



31-Pin 4mm x 4mm QFN